NSN 5961-01-111-7747

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-111-7747 **Inclosure Material:** Glass **Overall Length:** Between 0.120 inches and 0.200 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.060 inches and 0.090 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 40.0 reverse voltage, peak **Current Rating Per Characteristic:** 10.00 milliamperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80131-release4724 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0